INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)						Beaumon	t-26	10/552,546			
	TIME	yavı A	Use several sheets if necessar	ry)	Applicant(s) Bonnot et al.						
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	18g	PETR	<u></u>	U.S	. PATENT	DOCUMENTS					
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		EP 1134304 A2 / EP 1291890 A2 ·		09/19/01	Europe						
				03/12/03	Europe						
				OTHER E	OCUMEN	TS (Including Au	thor, Title, Date, Po	ertinent Pages, Et	c.)		
Marty L., et al.,"Batch processing of nanometer-scale electrical circuitry based on in-situ grown single-walled carbon nanotubes", MICROELECTRONIC ENGINEERING, ELSEVIER PUBLISHERS BV, AMSTERDAM, NL, vol. 61-62, Ju 2002, pages 485-489.										n -62, July	
	Jang J. W. et al, "Metallic conductivity in bamboo-shaped multiwalled carbon nanotubes", SOLID STATE COMMUNICATIONS, 2002, ELSEVIER, USA, vol. 122, no. 11, 2002, pages 619-622.										
EXAMINER						DATE CONSIDERED					
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	Lee C. J., et al., "Growth and structure of carbon nanotubes produced by thermal chemical vapor deposition", CARBON, XX, XX, vol. 39, no. 12, October 2001, pages 1891-1896									RBON,
		/ International Search Report dated September 2, 200r for related French Patent Application No. FR 03/04830 of April 17, 2003.								
EXAMINE	ER	/	Daniel Miller/			DATE CONSIDERED	03/13/20)11		
			ference considered, whether			I nance with MPEP 609; Draw	line through	citation if not in o	conformanc	e and not